



## HIGH DENSITY MOUNTING PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS

### APPROVALS

- UL recognised, File No. E91231

### DESCRIPTION

The TLP621-1, TLP621-2, TLP621-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

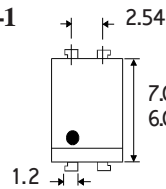
### FEATURES

- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio ( 50% min)
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High BV<sub>CEO</sub> ( 55Vmin )
- All electrical parameters 100% tested
- Custom electrical selections available

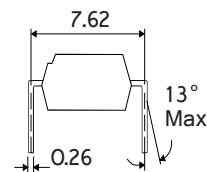
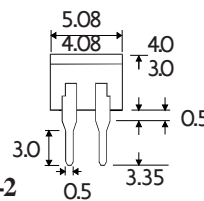
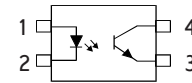
### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

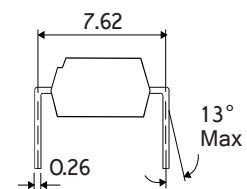
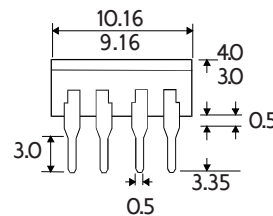
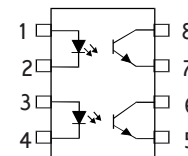
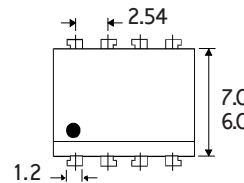
TLP621-1



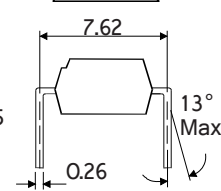
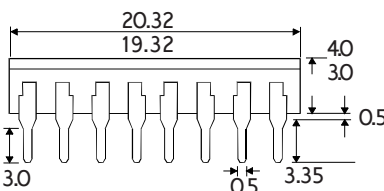
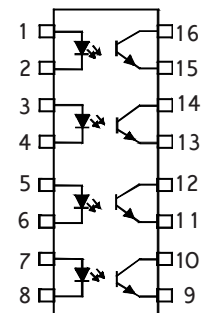
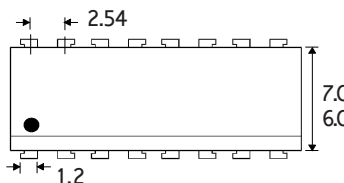
Dimensions in mm



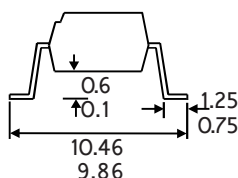
TLP621-2



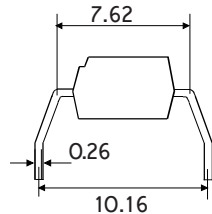
TLP621-4



OPTION SM  
SURFACE MOUNT



OPTION G



### ISOCOM COMPONENTS LTD

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**ABSOLUTE MAXIMUM RATINGS**  
(25°C unless otherwise specified)

Storage Temperature \_\_\_\_\_ -55°C to + 125°C  
 Operating Temperature \_\_\_\_\_ -55°C to + 100°C  
 Lead Soldering Temperature  
 (1/16 inch (1.6mm) from case for 10 secs) 260°C

**INPUT DIODE**

Forward Current \_\_\_\_\_ 50mA  
 Reverse Voltage \_\_\_\_\_ 5V  
 Power Dissipation \_\_\_\_\_ 70mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage  $BV_{CEO}$  \_\_\_\_\_ 55V  
 Emitter-collector Voltage  $BV_{ECO}$  \_\_\_\_\_ 6V  
 Power Dissipation \_\_\_\_\_ 150mW

**POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 200mW  
 (derate linearly 2.67mW/°C above 25°C)

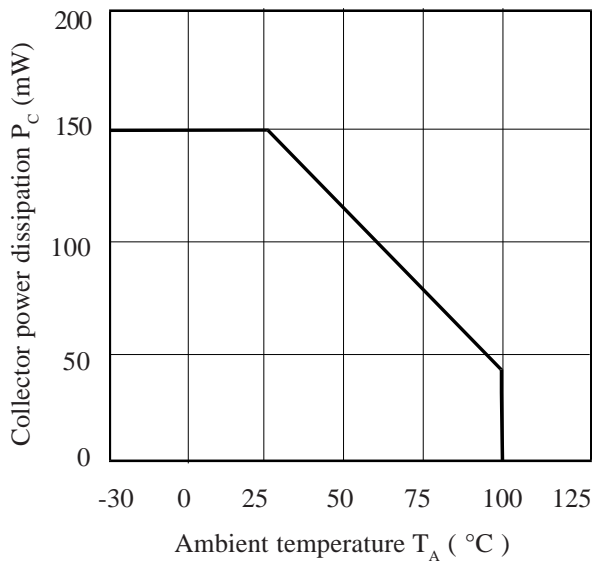
**ELECTRICAL CHARACTERISTICS (  $T_A = 25^\circ\text{C}$  Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ )	1.0	1.15	1.3	V	$I_F = 10\text{mA}$ $I_R = 10\mu\text{A}$ $V_R = 5\text{V}$
	Reverse Voltage ( $V_R$ )	5			V	
	Reverse Current ( $I_R$ )			10	$\mu\text{A}$	
Output	Collector-emitter Breakdown ( $BV_{CEO}$ ) ( Note 2 )	55			V	$I_C = 0.5\text{mA}$ $I_E = 100\mu\text{A}$ $V_{CE} = 24\text{V}$
	Emitter-collector Breakdown ( $BV_{ECO}$ )	6			V	
	Collector-emitter Dark Current ( $I_{CEO}$ )			100	nA	
Coupled	Current Transfer Ratio (CTR) (Note 2) TLP621-1, TLP621-2, TLP621-4	50		600	%	$5\text{mA } I_F, 5\text{V } V_{CE}$
	CTR selection available GB	100		300	%	
	BL	200		600	%	
	GR	30			%	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$ GB			0.4	V	$8\text{mA } I_F, 2.4\text{mA } I_C$ $1\text{mA } I_F, 0.2\text{mA } I_C$ See note 1 See note 1 $V_{IO} = 500\text{V}$ (note 1) $V_{CC} = 10\text{V}$ , $I_C = 2\text{mA}, R_L = 100\Omega$
	Input to Output Isolation Voltage $V_{ISO}$	5300			$V_{RMS}$	
		7500			$V_{PK}$	
	Input-output Isolation Resistance $R_{ISO}$	$5 \times 10^{10}$			$\Omega$	
	Rise Time tr		2		$\mu\text{s}$	
	Fall Time tf		3		$\mu\text{s}$	
	Turn-on Time ton		3		$\mu\text{s}$	
	Turn-off Time toff		3		$\mu\text{s}$	

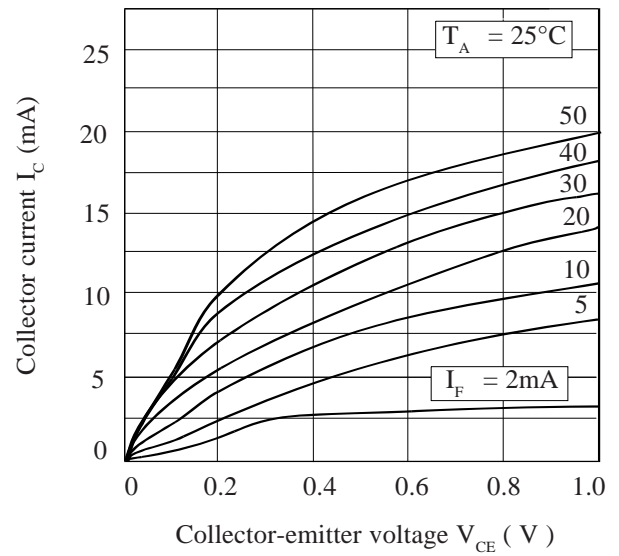
Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

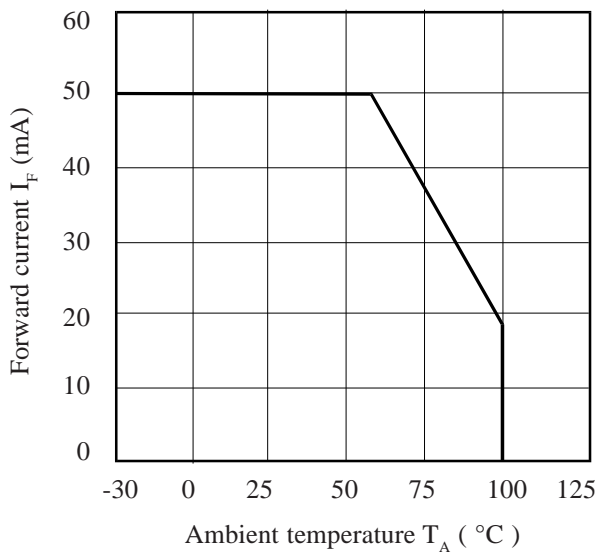
**Collector Power Dissipation vs. Ambient Temperature**



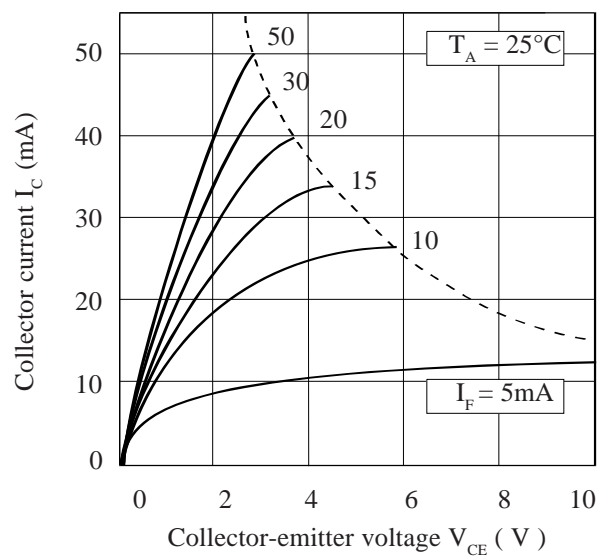
**Collector Current vs. Low Collector-emitter Voltage**



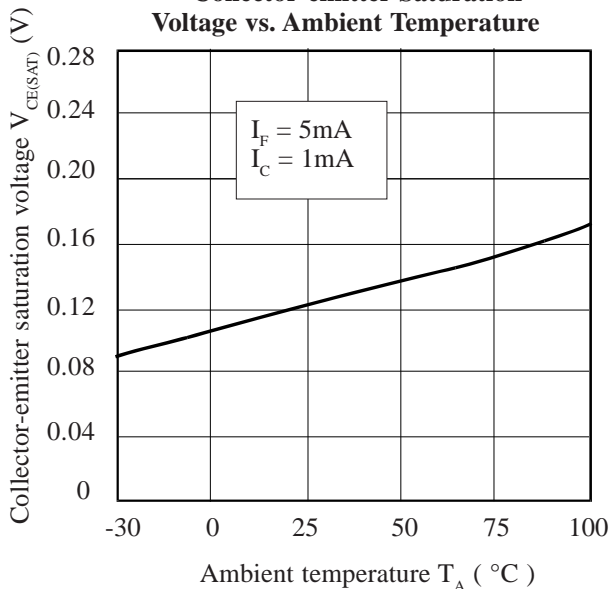
**Forward Current vs. Ambient Temperature**



**Collector Current vs. Collector-emitter Voltage**



**Collector-emitter Saturation Voltage vs. Ambient Temperature**



**Current Transfer Ratio vs. Forward Current**

